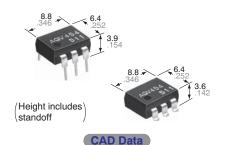
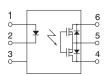
# Panasonic ideas for life

Normally closed DIP6-pin type Low on-resistance with 250V/400V load voltage PhotoMOS<sup>®</sup>
HE 1 Form B
(AQV450, AQV454H)



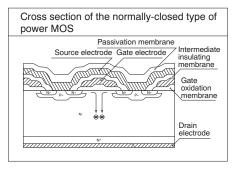
mm inch



### **FEATURES**

# 1. 1 Form B (Normally-closed) type with low on-resistance

This has been achieved thanks to the built-in MOSFET processed by our proprietary method, DSD (Double-diffused and Selective Doping) method.



# 2. Controls low-level analog signals PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without

#### 3. High sensitivity and low onresistance

Can control max. 0.2 A load current with 5 mA input current. Low on-resistance of typ. 5.5  $\Omega$  (AQV453).

# 4. Reinforced insulation 5,000 V type also available.

More than 0.4 mm .016 inch internal insulation distance between inputs and outputs. Conforms to IEC950 (reinforced insulation).

### TYPICAL APPLICATIONS

- Security equipment
- High-speed inspection machines
- Measuring instruments
- Telephone equipment
- Sensing equipment

## **TYPES**

	I/O isolation	Output rating*				Part	Packing quantity			
		Load	Load current	Package ·	Through hole terminal Surface-mount terminal					
					Tube packing style		Tape and reel packing style			
							Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side	Tube	Tape and reel
AC/DC dual use	1,500 V AC	250 V	50 V 200 mA		AQV453	AQV453A	AQV453AX	AQV453AZ	1 tube contains:	
		, , , , , , ,	400 V	150 mA	DIP6-pin	AQV454	AQV454A	AQV454AX	AQV454AZ	50 pcs. 1 batch contains:
	Reinforced 5,000 V AC	400 V	150 MA		AQV454H	AQV454HA	AQV454HAX	AQV454HAZ	500 pcs.	

<sup>\*</sup> Indicate the peak AC and DC values.

Note: The surface mount terminal indicator "A" and the packing style indicator "X" or "Z" are not marked on the relay.

distortion.

## **RATING**

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

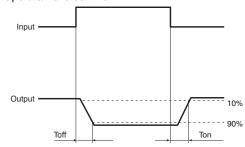
Item		Symbol	Type of connection	AQV453(A)	AQV454(A)	AQV454H(A)	Remarks
	LED forward current	lF		50 mA			
loout	LED reverse voltage	VR		5 V			
Input	Peak forward current IFP 1 A			f = 100 Hz, Duty factor = 0.1%			
	Power dissipation	Pin	1 \ [	75 mW			
Output	Load voltage (peak AC)	VL		250 V	400 V		
	Continuous load current	l <sub>L</sub>	Α	0.2 A	0.15 A		A connection: Peak AC, DC B, C connection: DC
			В	0.3 A	0.18 A		
			С	0.4 A	0.25 A		
	Peak load current	<b>I</b> PEAK		0.6 A	0.5 A		A connection: 100 ms (1 shot), V <sub>L</sub> = DC
	Power dissipation	Роит		360 mW			
Total power dissipation		Рт		410 mW 1,500 V AC 5,000 V AC			
I/O isolation voltage		Viso					
Temperature limits	Operating	Topr		-40°C to +85°C -40°F to +185°F		Non-condensing at low temperatures	
	Storage	Tstg		-40°C to +100°C −40°F to +212°F			

# HE 1 Form B (AQV45O, AQV454H)

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item			Symbol	Type of connection	AQV453(A)	AQV454(A)	AQV454H(A)	Remarks
Input	LED operate (OFF) current	Typical	l <sub>Foff</sub>	_	1 mA	0.9 mA	1.4 mA	I∟= Max.
	LED operate (OFF) current	Maximum	IFoff		3 mA			TIL = IVIAX.
	LED reverse (ON) current	Minimum	IFon		0.4 mA			IL = Max.
iliput	LED reverse (ON) current	Typical	IFON		0.9 mA	0.8 mA	1.3 mA	IL = IVIAX.
	LED dropout voltage	Typical	VF	_	1.25 V (1.14 V at I⊧=5 mA)			I <sub>F</sub> = 50 mA
	LLD dropout voltage	Maximum	VF		1.5 V			
	On resistance	Typical	Ron	A	$5.5~\Omega$	11 Ω		I <sub>F</sub> = 0 mA I <sub>L</sub> = Max. Within 1 s on time
		Maximum			8 Ω	16 Ω		
		Typical	Ron	В	2.7 Ω	6.3 Ω		I <sub>F</sub> = 0 mA I <sub>L</sub> = Max. Within 1 s on time
Output		Maximum			4 Ω	8 Ω		
		Typical	_	С	1.4 Ω	3.1 Ω		I <sub>F</sub> = 0 mA I <sub>L</sub> = Max. Within 1 s on time
		Maximum	Ron		2 Ω	4 Ω		
	Off state leakage current	Maximum	ILeak	_	1 μΑ	1 μΑ	10 μΑ	I <sub>F</sub> = 5 mA V <sub>L</sub> = Max.
	Operate (OFF) time*	Typical	Toff	_	1.52 ms	1.2 ms	1.8 ms	IF = 0 mA $\rightarrow$ 5 mA IL = Max. IF = 5 mA $\rightarrow$ 0 mA
Transfer characteristics	Operate (OFF) time	Maximum			3 ms	2.0 ms	3.0 ms	
	Reverse (ON) time*	Typical	- Ton	_	0.4 ms	0.36 ms	0.4 ms	
		Maximum	I on			1 ms		I∟ = Max.
	I/O capacitance	Typical	Ciso	_	1.3 pF			f = 1 MHz V <sub>B</sub> = 0 V
	ио сараспансе	Maximum			3 pF			
	Initial I/O isolation resistance	Minimum	Riso	_	1,000 MΩ		500 V DC	

<sup>\*</sup>Operate/Reverse time



## RECOMMENDED OPERATING CONDITIONS

Please obey the following conditions to ensure proper relay operation and resetting.

Item	Symbol	Recommended value	Unit	
Input LED current	lF	Standard type: 5 Reinforced insulation type: 5 to 10	mA	

- Dimensions
- Schematic and Wiring Diagrams
- Cautions for Use
- These products are not designed for automotive use.

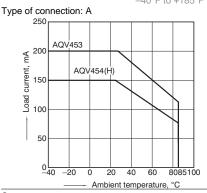
If you are considering to use these products for automotive applications, please contact your local Panasonic technical representative.

Please refer to our information on PhotoMOS Relays for Automotive Applications.

#### REFERENCE DATA

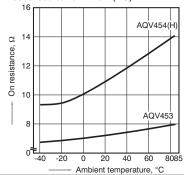
 Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C

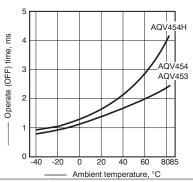


2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6; LED current: 0 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



Operate (OFF) time vs. ambient temperature characteristics
 LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)

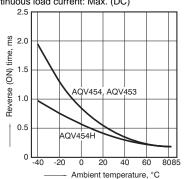


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# HE 1 Form B (AQV45O, AQV454H)

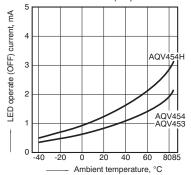
 Reverse (ON) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



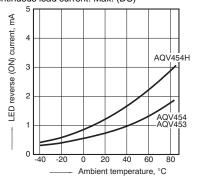
5. LED operate (OFF) current vs. ambient temperature characteristics

Load voltage: Max. (DC); Continuous load current: Max. (DC)



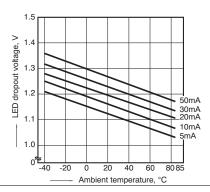
6. LED reverse (ON) current vs. ambient temperature characteristics

Load voltage: Max. (DC); Continuous load current: Max. (DC)



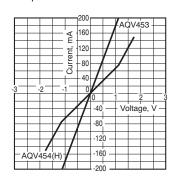
7. LED dropout voltage vs. ambient temperature characteristics

LED current: 5 to 50 mA



 Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 4 and 6; Ambient temperature: 25°C 77°F

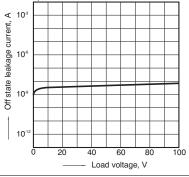


 Off state leakage current vs. load voltage characteristics

Sample: AQV454;

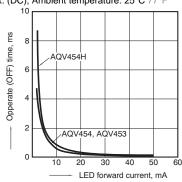
Measured portion: between terminals 4 and 6;

Ambient temperature: 25°C 77°F



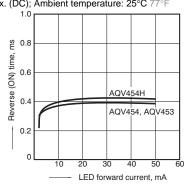
10.Operate (OFF) time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature:  $25^{\circ}C$  77°F



11.Reverse (ON) time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



12.Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 4 and 6; Frequency: 1 MHz; Ambient temperature: 25°C 77°F

